

**Matched GaAs SP4T Switch,
5 - 2000 MHz**

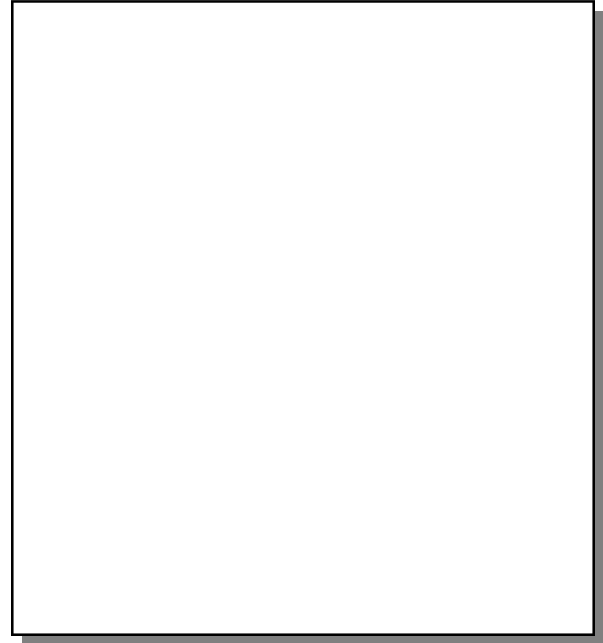
**SW-261-PIN
V3**

Features

- Low Insertion Loss, 1.0 dB Typical
- Fast Switching Speed, 20 nS Typical
- Ultra Low DC Power Consumption, 0.3 mA Typical
- Integral TTL Driver
- 50 Ohm Nominal Impedance
- MIL-STD-883 screening available

Description

Functional Block Diagram



Ordering Information

Part Number	Package
SW-261-PIN	FP-17

Note: Reference Application Note M513 for reel size information.
Note: Die quantity varies.

Truth Table

Control Input				Condition of Switch			
"1" = Logic High				RF Common to Each RF Port			
CTL 1	CTL 2	CTL 3	CTL 4	RF1	RF2	RF3	RF4
1	0	0	0	ON	OFF	OFF	OFF
0	1	0	0	OFF	ON	OFF	OFF
0	0	1	0	OFF	OFF	ON	OFF
0	0	0	1	OFF	OFF	OFF	ON

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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Electrical Specifications: $T_A = -55^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ ¹

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	5 - 2000 MHz	dB	2.1	—	—
		5 - 1000 MHz	dB	1.6	—	—
		5 - 500 MHz	dB	1.4	—	—
VSWR	—	5 - 2000 MHz	Ratio	—	—	2.5:1
		5 - 1000 MHz	Ratio	—	—	1.8:1
		5 - 500 MHz	Ratio	—	—	1.4:1
Isolation	—	5 - 2000 MHz	dB	35	—	—
		5 - 1000 MHz	dB	36	—	—
		5 - 500 MHz	dB	42	—	—
Trise, Tfall Ton, Toff Transients	50% CTL to 90/10% RF In-band	—	nS	—	7	—
		—	nS	—	20	—
		—	mV	—	80	—
1 dB Compression	Input Power	500 - 2000 MHz	dBm	—	+27	—
		50 MHz	dBm	—	+21	—
IP ₂	For two tone input power up to +13 dBm	500 - 2000 MHz	dBm	—	+68	—
		50 MHz	dBm	—	+60	—
IP ₃	For two tone input power up to +13 dBm	500 - 2000 MHz	dBm	—	+27	—
		50 MHz	dBm	—	+21	—
Bias Power	+5 VDC @ 0.30 mA Typ	—	mA	—	—	1

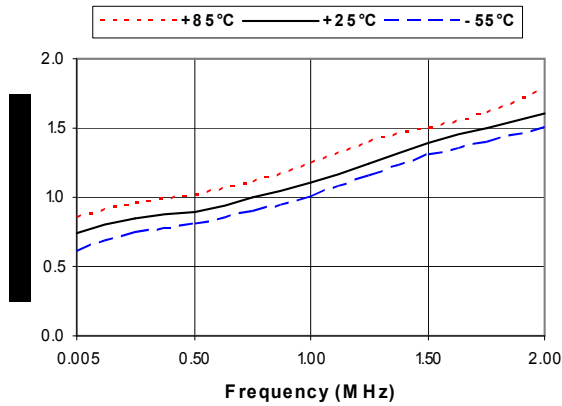
1. All specifications apply when operated with bias voltages of +5 VDC and 50 ohm impedance at all RF Ports.

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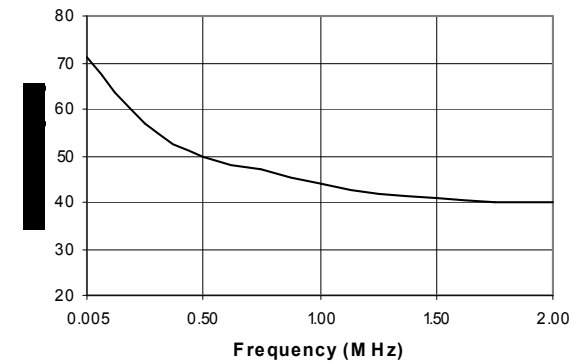
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Typical Performance Curves

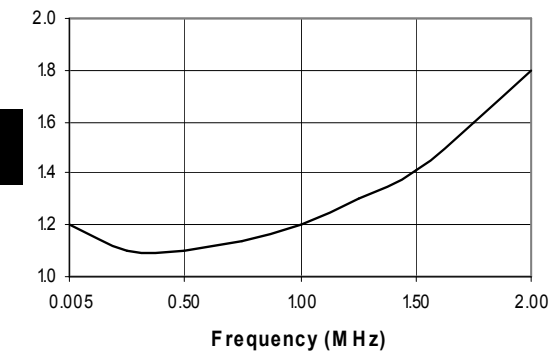
Insertion Loss



Isolation



VSWR



Schematic

